

Control of quantum interference in molecular junctions: Understanding the origin of Fano and anti-resonances

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We investigate within a coarse-grained model the conditions leading to the appearance of Fano resonances or anti-resonances in the conductance spectrum of a generic molecular junction with a side group (T-junction). By introducing a simple graphical representation (parabolic diagram), we can easily visualize the relation between the different electronic parameters determining the regimes where Fano resonances or anti-resonances in the low-energy conductance spectrum can be expected. The results obtained within the coarse-grained model are validated using density-functional based quantum transport calculations in realistic T-shaped molecular junctions.

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Introduction— Quantum interference (QI) effects in electron transport have been broadly studied in the field of mesoscopic physics and quantum dots [1, 2], and their appearance in molecular junctions had been suggested in the early 1990s from studies on electron transfer [3, 4]. In the context of charge transport in molecular scale electronic devices, QI effects have drawn increasing attention over the past years due to their unique spectral features, manifested in the conductance spectra of the junctions, and which make them very attractive for tuning the low energy electrical response of molecular-scale systems [1, 5–18]. For instance, since QI effects introduce additional peaks or dips in the conductance spectrum, it may be expected that they can considerably change the on/off ratios and thermoelectric performance of molecular junctions [16, 19]. Moreover, since it is possible to infer from the analysis of transport line shapes the molecular electronic structure as well as the topological connectivity of the molecular junctions, QI related effects might be also exploited for sensor or interferometer applications by monitoring the changes of the transmission spectrum as function of e.g. a magnetic field.

It is therefore of great theoretical and practical interest to provide simple rules controlling the emergence of different types of QI effects like anti-resonances or Fano line shapes [5, 6, 12, 14, 18]. According to the lineshape, QI effects can manifest either as anti-resonances (negative, almost symmetric peaks) or as Fano resonances (asymmetric sharp peaks) [2, 9–11]. As a general qualitative trend, it has been shown that T-shaped [8, 10–12] or cyclic molecules [13] tend to exhibit QI effects in their transmission spectra.

Although many studies of QI effects have been conducted, the understanding of the origin of anti-resonances and Fano resonances as well as their classification are still under debate. For further development of single molecular devices exploiting QI effects, the precise relationship between electronic structure and QI needs to be understood. In particular, the origins of and the constraints on Fano and anti-resonance line shapes should be clarified. Although this can be achieved using extensive first-principle based calculations, it is also de-

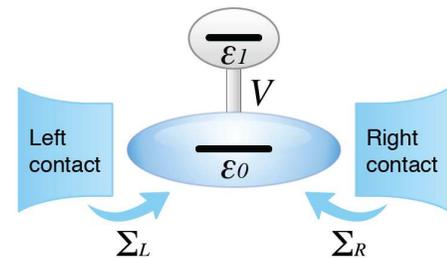


FIG. 1. Schematic image of a molecular junction with a side group considered in this work. A molecule consisting of two fragments is coupled between electrodes. The energies of two fragments are ε_0 and ε_1 . The transfer integral between them is set to V . $\Sigma_{L/R}$ represents the self energies due to coupling to the contacts.

sirable to provide simple rules relating electronic structure and QI signatures in molecular scale systems.

Here, we first study the transmission properties of a T-shaped toy molecule. Using it as a starting point, we describe the conditions under which the two types of QI line shapes (anti-resonances and Fano resonances) may appear. Hereby we introduce a simple graphical representation –called from now on parabolic diagram for the sake of simplicity, see also Fig. 2– to predict the type of QI effect as well as their line shape in an accurate way. In the second part of this study, we validate our minimal model approach by computing on a first-principle basis the linear conductance of realistic molecular junctions with different topologies and displaying QI related features, finding a very nice agreement with the parabolic diagram approach.

Minimal model of a T-shaped molecule—We consider a generic molecular wire with a side group as schematically shown in Fig. 1. The system is attached to left and right electronic baths only through the central wire, i.e. the side groups do not directly couple to the electrodes. To analyze QI effects in such a configuration, we can mainly focus on the low-energy (near the Fermi level E_F) features of the conductance spectrum. Hence, a simple coarse-grained can be formulated, which does not need to include the full electronic spectrum

of the system. Consider the retarded Green's function G^r of the molecule attached to the electrodes. It satisfies a spectral representation of the form [6, 20]:

$$G^r(E) = \sum_{i=1}^N \phi_i \psi_i^* / (E + i\delta - \epsilon_i). \quad (1)$$

Since the molecular system is coupled to a continuum of states (the electrodes) and is thus an open system, the eigenenergies ϵ_i are complex and the difference between left (ϕ_i) and right (ψ_i^*) eigenvectors building a bi-orthonormal set should be taken into account. The transmission through the system around energies $E \sim E_F$, is mainly affected by few molecular orbitals (MOs) around E since the contribution from deeper levels is expected to be small because of the large denominators in eq. (1). As a result, charge transport in the model system of Fig. 1 can be simplified to a two-state model with energies ϵ_0 for the central site and ϵ_1 for the side group as long as we focus on the transmission around these energies. The coupling between the two states is set to V . In real systems, ϵ_0 is expected to correspond to one of the frontier MOs, which is delocalized over the main chain and is responsible for charge transport, while ϵ_1 corresponds to MOs of the side-functional group, which have the strongest overlap with the ϵ_0 states.

Within Landauer's theory [20], the transmission function can be computed via $T(E) = \text{Tr}[G^r \Gamma_L G^a \Gamma_R]$, where $\Gamma_{L/R}$ correspond to the spectral densities of the electrodes. Since the coupling to the electrodes and to the side group can be represented by three self-energy terms, $\Sigma_{L/R}$ (due to the left/right reservoirs) and $\Sigma_S = V^2/(E - \epsilon_1)$, the retarded Green's function of the molecular junction can be written as: $[G^r]^{-1}(E) = (E + i\delta) - \epsilon_0 - \Sigma_L - \Sigma_R - V^2/(E - \epsilon_1)$. If we neglect for simplicity the energy dependence of the electrode self-energies within the so called wide-band limit (WBL), the contribution of the reservoirs can be written as $\Sigma_{L/R} = -i\gamma_{L/R}$. The broadening functions $\Gamma_{L/R}$ are then defined as $\Gamma_{L/R} \equiv i[\Sigma_{L/R} - \Sigma_{L/R}^\dagger] = 2\gamma_{L/R}$. Hereafter for simplicity, we assume $\gamma_{L/R} = \gamma$. The transmission function is then simply given by:

$$T(E) = \frac{4\gamma^2}{(E - \epsilon_0 - \frac{V^2}{E - \epsilon_1})^2 + 4\gamma^2} \quad (2)$$

Starting from this formula, we show below that (i) an anti-resonance at $E = \epsilon_1$ and two symmetric resonance peaks at ϵ_{bond} and ϵ_{anti} appear when $|\epsilon_1 - \epsilon_0|/|V|$ is small, (ii) the system presents asymmetric Fano line shapes when $|\epsilon_1 - \epsilon_0|/|V|$ is large. The transition regime is however not universally defined, but depends on the specific values of the electronic parameters.

From eq. (2), it is obvious that when the term $(E - \epsilon_0 - V^2/(E - \epsilon_1))^2$ is a minimum, $T(E)$ attains its maximum. This is a Breit-Wigner-type resonant peak with width γ . The positions of the peaks are given by the solutions of the quadratic equation:

$$(E - \epsilon_0)(E - \epsilon_1) - V^2 = 0, \quad (3)$$

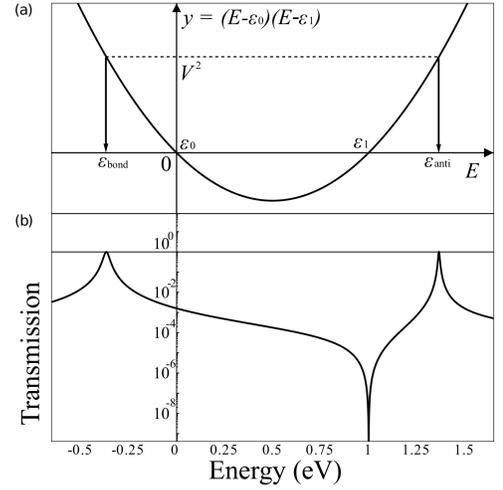


FIG. 2. (a) Parabolic diagram showing the relation between onsite energies $\epsilon_{0,1}$, coupling V and resonant peaks $\epsilon_{\text{bond,anti}}$. (b) The transmission function obtained from Eq. (3) with $\epsilon_0 = 0.0$ eV, $\epsilon_1 = 1.0$ eV, $V^2 = 0.5$ eV², and $\gamma = 0.01$ eV.

with solutions $\epsilon_{\text{bond}}, \epsilon_{\text{anti}}$ given by $2\epsilon_{\text{bond,anti}} = \epsilon_0 + \epsilon_1 \pm \sqrt{(\epsilon_0 - \epsilon_1)^2 + 4V^2}$, where the transmission maxima take place [2, 10, 11, 19]. Note that the two solutions are always real. At this point we introduce a graphical representation (parabolic diagram) by plotting the reduced variable $y = (E - \epsilon_0)(E - \epsilon_1)$ as a function of the energy E , as shown in Fig. 2(a). Using this diagram, the peak and dip positions as well as their relation to the relevant electronic parameters $\epsilon_0, \epsilon_1, V, \epsilon_{\text{bond}}, \epsilon_{\text{anti}}$ can easily be visualized. The system gives a dip at $E = \epsilon_1$ with $T(E) = 0$, since the denominator in eq. (2) diverges, $\lim_{E \rightarrow \epsilon_1 \pm 0} \frac{V^2}{E - \epsilon_1} = \pm\infty$. Therefore, the energetic position of positive resonance peaks ($E = \epsilon_{\text{bond}}, \epsilon_{\text{anti}}$) and negative peaks ($E = \epsilon_1$) in $T(E)$ can be estimated from the parabolic diagram in Fig. 2(a) or by using more sophisticated numerical methods. To illustrate this point further, if one would like to examine the QI effects of molecular wires having e.g. a conducting state at $\epsilon_0 = 0.0$ eV and a localized state at $\epsilon_1 = 1.0$ eV with coupling $V^2 = 0.5$ eV², it is possible to estimate the position of the Breit-Wigner-type resonance and of an anti-resonance by drawing the diagram as in Fig. 2(a). Fig. 2(b) presents the transmission function calculated from eq. (2) using the same parameters. We can see that the position of the negative and positive peaks completely matches with the features of the parabolic diagram. More interestingly, it is also possible to estimate the coupling V from the position of the positive and negative peaks in the transmission function using this parabolic diagram. If the peak ($\epsilon_{\text{bond,anti}}$) and dip (ϵ_1) positions can be resolved experimentally, the orbital energy (ϵ_0) and the electronic coupling (V) are uniquely determined.

Next, we address the case of a Fano resonance. When one of the solutions of eq. (3) is close to ϵ_1 , i.e. when $|\epsilon_1 - \epsilon_0|/|V|$ is large enough, the negative and positive peaks come close to-

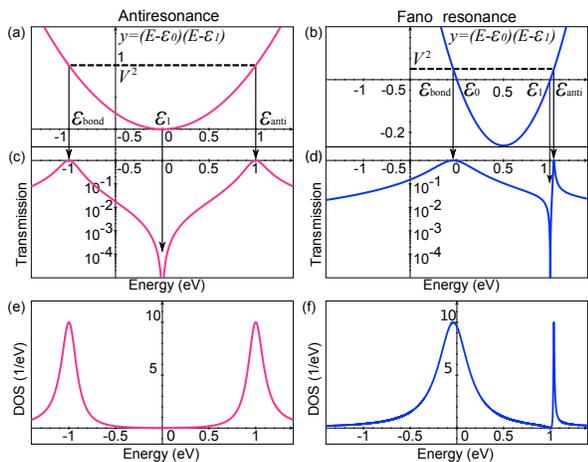


FIG. 3. The two types of QI through molecular junction in Fig. 1. To produce the anti-resonance, parameters are set as $\varepsilon_{0,1} = 0.0$ eV and $V = 1.0$ eV. To produce the Fano resonance, parameters are set as $\varepsilon_0 = 0.0$ eV, $\varepsilon_1 = 1.0$ eV and $V = 0.2$ eV.

gether leading to an asymmetric line shape, a Fano resonance. The condition for the anti-resonance is simply given by the $T(E) = 0$ with large energy spacing $|\varepsilon_{\text{anti}} - \varepsilon_1|$ or $|\varepsilon_{\text{bond}} - \varepsilon_1|$ with positive resonant peaks. This is satisfied by large $|V|$ with small $|\varepsilon_0 - \varepsilon_1|$. In the special case of $\varepsilon_0 = \varepsilon_1$, the anti-resonance shows a symmetric line shape at $E = \varepsilon_1$ [10, 19].

Minimal model of a T-shaped molecular junction: Dependence on the model parameters— Keeping the previously discussed conditions for the two types of QI effects in mind, we will examine how the transmission function behaves with different choices of ε_0 , ε_1 , and V using the parabolic diagram. Fig. 3 presents two types of QI effects of the system in Fig. 1. As discussed before, small $|\varepsilon_0 - \varepsilon_1|$ with large $|V|$ gives an anti-resonance (red in Fig. 3), while large $|\varepsilon_0 - \varepsilon_1|$ with small $|V|$ gives a Fano resonance (blue in Fig. 3). The condition of weak coupling $|V|$ for the Fano resonance agrees with the general interpretation of the Fano effect where the localized state interferes with a continuum. A critical difference between these QI effects is that an anti-resonance does not require a localized state at the position of a negative peak, while a Fano resonance does require a localized state at the position of the asymmetric peak.

We also investigated the coupling $|V|$ dependence and on-site energy $|\varepsilon_1|$ dependence of the QI effects. Fig. 4(a) presents the anti-resonance with different coupling strengths. In the weak coupling limit, the transmission merges down to a Breit-Wigner resonance. This is obvious from Eq. (3) and also from the parabolic diagram since the resonant peaks come closer to each other with decreasing V . Fig. 4(b) shows the on-site energy $|\varepsilon_1|$ dependence of the transmission. We can see the transition from anti-resonance to Fano resonance with larger $|\varepsilon_1 - \varepsilon_0|$. This is also interpreted from the parabolic diagram in Fig. 2(a) since the gradient of the parabola at $E = \varepsilon_1$ becomes steeper for increasing $|\varepsilon_1 - \varepsilon_0|$, which makes ε_1 and $\varepsilon_{\text{anti}}$ closer to each other. From these analysis, we conclude

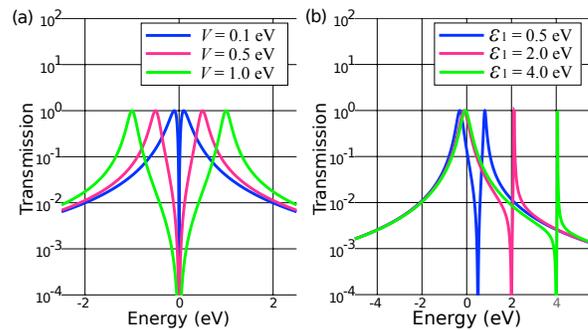


FIG. 4. (a) $|V|$ dependence of anti-resonance. On-site energies are set as $\varepsilon_{0,1} = 0.0$ eV. (b) ε_1 dependence of the transmission functions. On-site energies are set as $\varepsilon_0 = 0.0$ eV. The coupling strength $|V|$ is fixed to $V = 0.5$ eV. The transmission spectra gradually shifts from anti-resonance having symmetric negative peaks to Fano resonance having asymmetric peaks as $|\varepsilon_0 - \varepsilon_1|$ is increased.

that weak coupling $|V|$ and weak broadening γ with large $|\varepsilon_0 - \varepsilon_1|$ are the optimal conditions for Fano resonance.

Validation of the parabolic diagram: first-principle transport calculations— In order to demonstrate the relevance of the parabolic diagram for realistic systems, we have modeled two molecular wires with side groups as shown in Fig. 5, which display Fano resonances and anti-resonances. As electrodes, we chose semi-infinite Si slabs with a (111) termination and surface dangling bonds saturated with hydrogens. We used the gDFTB program [21] for the transmission calculations, which is based on a density-functional tight binding method [22]. All transmission calculations were performed after structure relaxation in the same way as in Ref. [23]

At first, in order to generate a Fano resonance, we modeled a molecular wire (model A in Fig. 5(b)) by weakly coupling a side-group to the main chain such that the energy difference between the eigenstate responsible for the conduction (ε_0) and the localized fragment MO at the side group (ε_1) is large. To have weak electronic coupling between them, the side group is vertically grafted to the main chain. We used carboxylic acids for the linkers connecting between the molecule and the Si contacts. Fig. 5 summarizes the transmission and total (DOS) and projected (PDOS) density of states plots of the modeled systems. In the absence of the side group, the valley with low transmission spreads from the HOMO to the Fermi energy, while in the presence of the side group a Fano resonance appears around $E = -4.9$ eV due to the interference between the localized state from the side group and the conduction state. We can clearly see the localized state around $E = -4.9$ eV originating from the side group in PDOS plot in Fig. 5(d). The coupling strength V and the energy difference $|\varepsilon_0 - \varepsilon_1|$ are estimated to be 0.062 eV and 0.370 eV from the transmission line shape in Fig. 5(d). As mentioned in the analysis of the coarse-grained model, these values with large $|\varepsilon_1 - \varepsilon_0|/|V| = 5.968$ satisfy the condition for Fano resonance.

Next, in order to have an anti-resonance, we modeled a

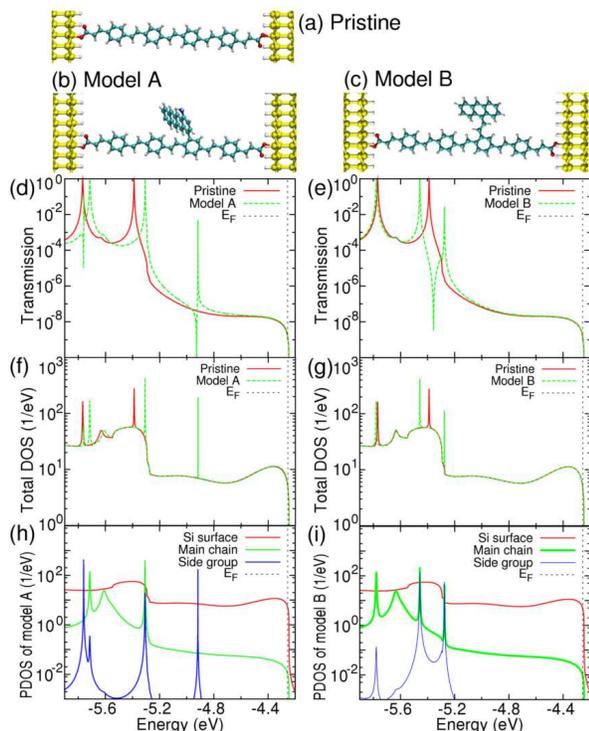


FIG. 5. Demonstration of Fano resonance (left panels) and anti-resonance (right panels).

molecular wire (model B Fig. 5(c)) by strongly coupling a side-group to the main chain. For strong electronic coupling between them, the side group is linked to the main chain using an sp_2 linker. We can see that the resonant peak of the pristine system at -5.4 eV in Fig. 5(e) splits into bonding and anti bonding peaks after the coupling to the side group because of the strong electronic interaction between the side group and the main chain. The transmission of model B gives an anti-resonance peak between the bonding and anti bonding peaks as expected. From the PDOS plot in Fig. 5(i), it is clear that the states of the side group are not localized anymore (thus not satisfying the condition for Fano resonance) but delocalized on the main chain because of the strong electronic interaction between the side group and the main chain. The coupling strength V and the energy difference $|\varepsilon_0 - \varepsilon_1|$ are estimated to be 0.090 eV and 0.023 eV from the transmission function in Fig. 5(e). As mentioned in the analysis of the coarse-grained model, these values with large V compared to $|\varepsilon_0 - \varepsilon_1|$ satisfy the condition for anti-resonance ($|\varepsilon_1 - \varepsilon_0|/|V| = 0.256$).

Conclusion— We have derived conditions for Breit-Wigner type normal resonant peaks as well as for quantum interference related states (Fano resonances and anti-resonances) in T-shaped molecular junctions using a coarse-grained model and clarified the origins of the two QI-based effects using a simple graphical representation (parabolic diagram). With its help, we can easily explain the two QI related effects in realistic molecular junctions, thus validating our minimal for-

mulation. Our results are expected to provide a very helpful guideline for building functional molecular devices which exploit QI effects. Usually, in planar organic π -systems, the electronic coupling V between the main molecular chain and the side groups is strong. This situation is closer to the condition for anti-resonance than for a Fano resonance and, hence, this is the reason why many organic systems display anti-resonances while Fano resonances are rarely seen.

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